

74LV244

Octal buffer/line driver (3-state)

Rev. 3 — 11 March 2014

Product data sheet

1. General description

The 74LV244 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC244 and 74HCT244.

The 74LV244 is an octal non-inverting buffer/line driver with 3-state outputs. The output enable inputs $\overline{1OE}$ and $\overline{2OE}$ control the 3-state outputs. A HIGH on $\overline{nOE}$ causes the outputs to assume a high impedance OFF-state. The 74LV244 is identical to the 74LV240 but has non-inverting outputs.

2. Features and benefits

- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between $V_{CC} = 2.7$ V and $V_{CC} = 3.6$ V
- Typical V_{OLP} (output ground bounce) < 0.8 V at $V_{CC} = 3.3$ V; $T_{amb} = 25$ °C
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at $V_{CC} = 3.3$ V; $T_{amb} = 25$ °C
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V

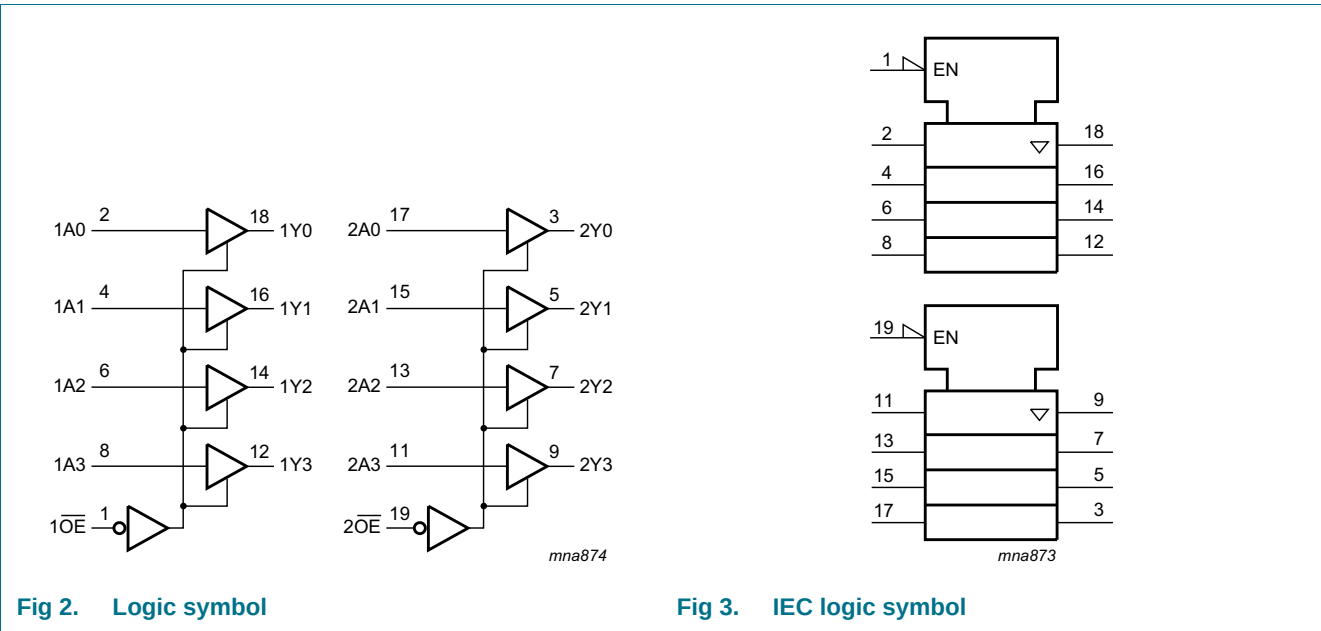
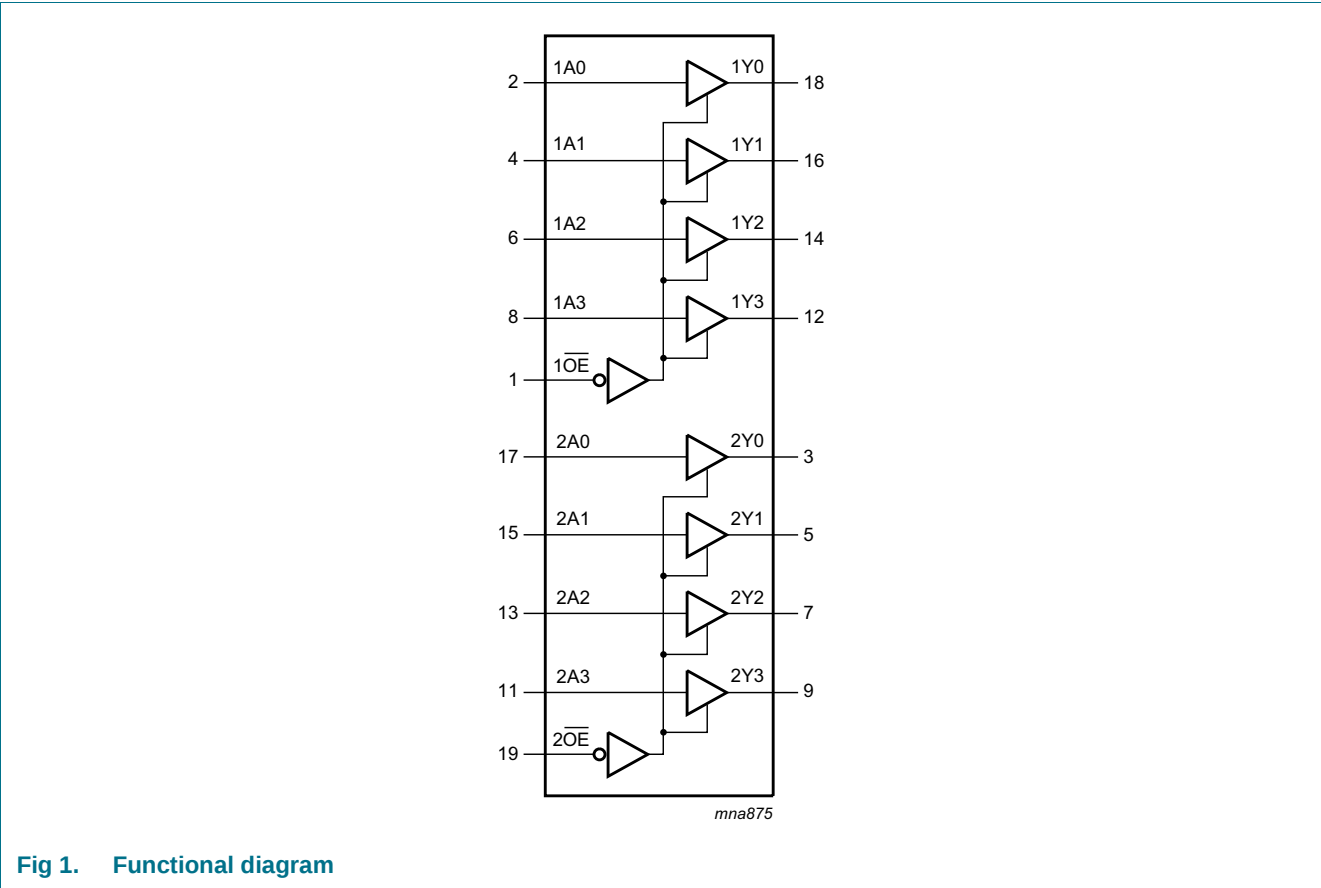
3. Ordering information

Table 1. Ordering information

Type number	Package	Name	Description	Version
	Temperature range			
74LV244N	−40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74LV244D	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74LV244DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74LV244PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1

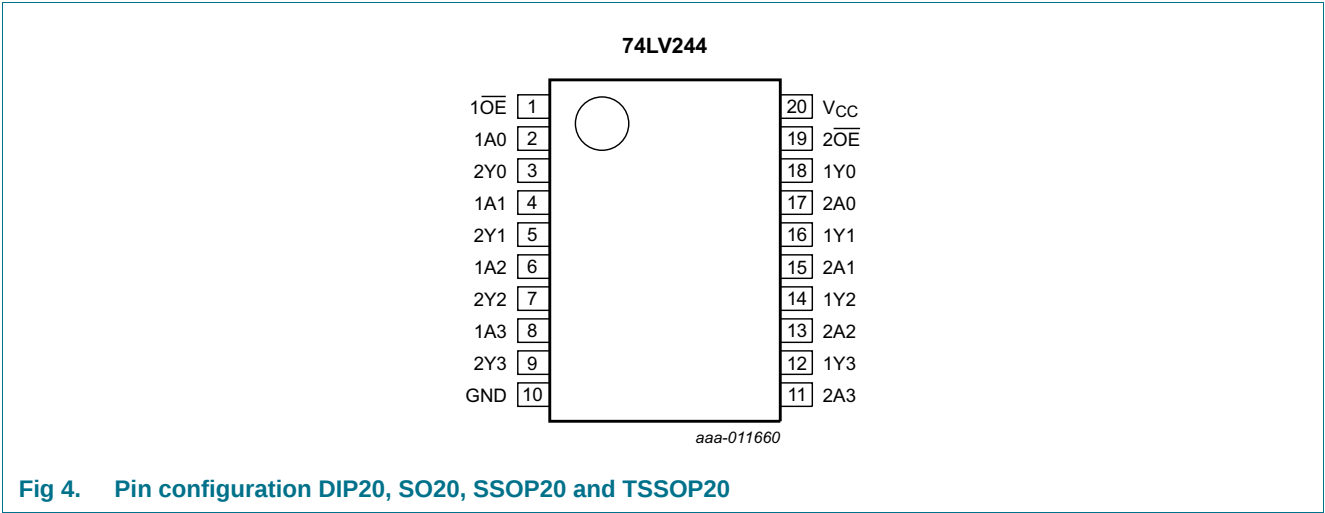


4. Block diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$\overline{1OE}, \overline{2OE}$	1, 19	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2Y0, 2Y1, 2Y2, 2Y3	3, 5, 7, 9	bus output
GND	10	ground (0 V)
2A0, 2A1, 2A2, 2A3	17, 15, 13, 11	data input
1Y0, 1Y1, 1Y2, 1Y3	18, 16, 14, 12	bus output
V _{CC}	20	supply voltage

6. Functional description

Table 3. Function table^[1]

Input		Output
$\overline{nOE}$	nAn	nYn
L	L	L
L	H	H
H	X	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	± 20	mA
I_{OK}	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	-	± 50	mA
I_O	output current	$-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$	-	± 35	mA
I_{CC}	supply current		-	70	mA
I_{GND}	ground current		-70	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$			
		DIP20 package [1]	-	750	mW
		SO20 [2]	-	500	mW
		SSOP20 and TSSOP20 [3]	-	400	mW

[1] For DIP20 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[2] For SO20 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP20 and TSSOP20 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage	[1]	1.0	3.3	5.5	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	-	+85	°C
			-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.0\text{ V}$ to 2.0 V	0	-	500	ns/V
		$V_{CC} = 2.0\text{ V}$ to 2.7 V	0	-	200	ns/V
		$V_{CC} = 2.7\text{ V}$ to 3.6 V	0	-	100	ns/V
		$V_{CC} = 3.6\text{ V}$ to 5.5 V	0	-	50	ns/V

[1] The LV is guaranteed to function down to $V_{CC} = 1.0\text{ V}$ (input levels GND or V_{CC}). DC characteristics are guaranteed from $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 5.5\text{ V}$.

9. Static characteristics

Table 6. Static characteristics

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{IH}	HIGH level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	0.7V _{CC}	-	V
V _{IL}	LOW level input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
		V _{CC} = 2.0 V	-	-	0.6	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	-	0.3V _{CC}	V
V _{OH}	HIGH level output voltage	V _I = V _{IH} or V _{IL} ; I _O = –100 µA						
		V _{CC} = 1.2 V	-	1.2	-	-	-	V
		V _{CC} = 2.0 V	1.8	2.0	-	1.8	-	V
		V _{CC} = 2.7 V	2.5	2.7	-	2.5	-	V
		V _{CC} = 3.0 V	2.8	3.0	-	2.8	-	V
		V _{CC} = 4.5 V	4.3	4.5	-	4.3	-	V
		V _I = V _{IH} or V _{IL}						
		V _{CC} = 3.0 V; I _O = –8 mA	2.40	2.82	-	2.20	-	V
V _{OL}	LOW level output voltage	V _I = V _{IH} or V _{IL} ; I _O = 100 µA						
		V _{CC} = 1.2 V	-	0	-	-	-	V
		V _{CC} = 2.0 V	-	0	0.2	-	0.2	V
		V _{CC} = 2.7 V	-	0	0.2	-	0.2	V
		V _{CC} = 3.0 V	-	0	0.2	-	0.2	V
		V _{CC} = 4.5 V	-	0	0.2	-	0.2	V
		V _{CC} = 3.0 V; I _O = 8 mA	-	0.25	0.40	-	0.50	V
		V _{CC} = 4.5 V; I _O = 16 mA	-	0.35	0.55	-	0.65	V
I _I	input leakage current	V _{CC} = 5.5 V; V _I = V _{CC} or GND	-	-	1.0	-	1.0	µA
I _{OZ}	3-State output OFF-state current	V _{CC} = 3.6 V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND	-	-	5	-	10	µA
I _{CC}	supply current	V _{CC} = 5.5 V; V _I = V _{CC} or GND; I _O = 0 A	-	-	20	-	160	µA
ΔI _{CC}	additional supply current	per input; V _{CC} = 2.7 V to 3.6 V; V _I = V _{CC} – 0.6 V	-	-	500	-	850	µA
C _I	input capacitance		-	3.5	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see [Figure 7](#)

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t _{pd}	propagation delay	1An to 1Yn; 2An to 2Yn; see Figure 5 ^[2]						
		V _{CC} = 1.2 V	-	50		-	-	ns
		V _{CC} = 2.0 V	-	17	24	-	31	ns
		V _{CC} = 2.7 V	-	13	17	-	23	ns
		V _{CC} = 3.0 V to 3.6 V	-	9	14	-	18	ns
		V _{CC} = 3.3 V; C _L = 15 pF	-	8.0	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	-	-	12	-	15	ns
t _{en}	enable time	1 $\overline{\text{OE}}$ to 1Yn; 2 $\overline{\text{OE}}$ to 2Yn; see Figure 6 ^[2]						
		V _{CC} = 1.2 V	-	65	-	-	-	ns
		V _{CC} = 2.0 V	-	22	39	-	49	ns
		V _{CC} = 2.7 V	-	16	29	-	36	ns
		V _{CC} = 3.0 V to 3.6 V	-	12	23	-	29	ns
		V _{CC} = 4.5 V to 5.5 V	-	-	19	-	24	ns
t _{dis}	disable time	1 $\overline{\text{OE}}$ to 1Yn; 2 $\overline{\text{OE}}$ to 2Yn; see Figure 6 ^[2]						
		V _{CC} = 1.2 V	-	60		-	-	ns
		V _{CC} = 2.0 V	-	22	34	-	43	ns
		V _{CC} = 2.7 V	-	17	24	-	32	ns
		V _{CC} = 3.0 V to 3.6 V	-	13	21	-	26	ns
		V _{CC} = 4.5 V to 5.5 V	-	-	16	-	19	ns
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC} ; V _{CC} = 3.3 V ^[3]	-	35	-	-	-	ns

[1] Unless otherwise stated, all typical values are measured at T_{amb} = 25 °C and nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

t_{en} is the same as t_{PZL} and t_{PZH}.

t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] C_{PD} is used to determine the dynamic power dissipation P_D = C_{PD} × V_{CC}² × f_i + Σ (C_L × V_{CC}² × f_o) (P_D in μW), where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

Σ (C_L × V_{CC}² × f_o) = sum of outputs;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

11. Waveforms

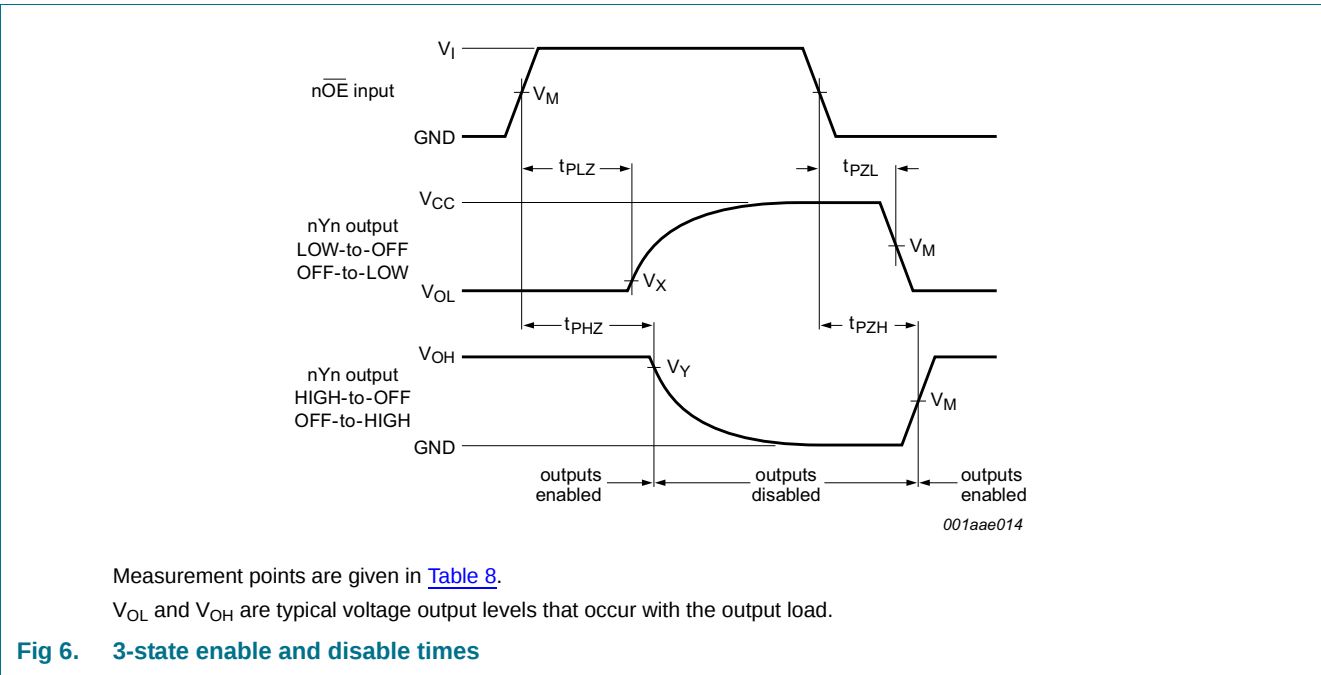
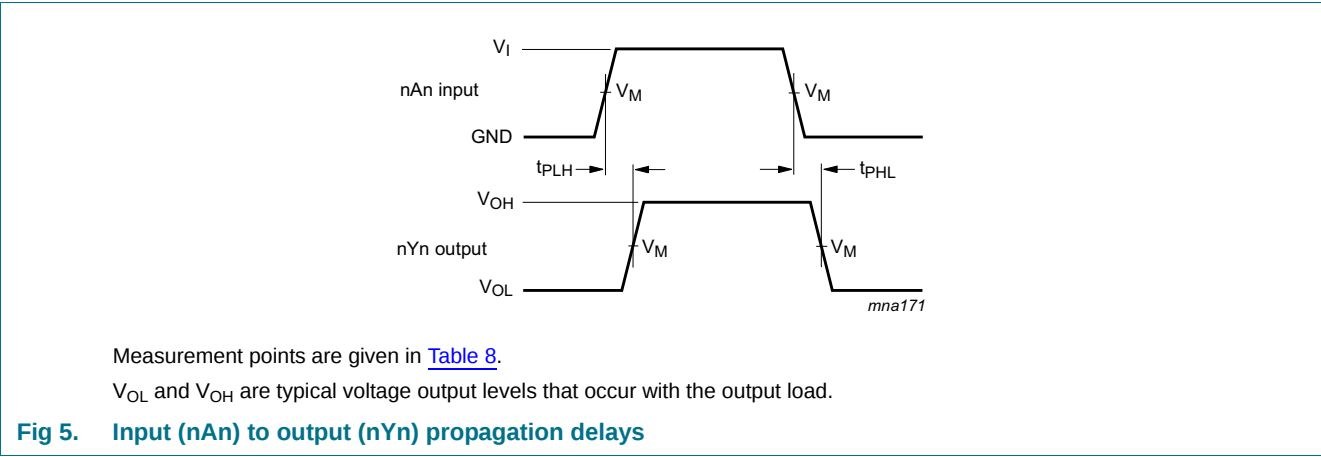
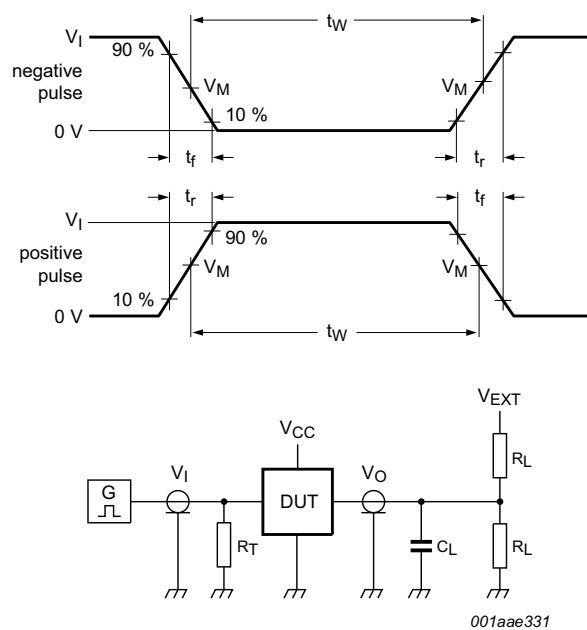


Table 8. Measurement points

Supply voltage	Input	Output		
V_{CC}	V_M	V_M	V_X	V_Y
< 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.1V_{CC}$	$V_{OH} - 0.1V_{CC}$
2.7 V to 3.6 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$
$\geq 4.5 V$	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.1V_{CC}$	$V_{OH} - 0.1V_{CC}$



Test data is given in [Table 9](#).

Definitions test circuit:

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 7. Test circuit for measuring switching times

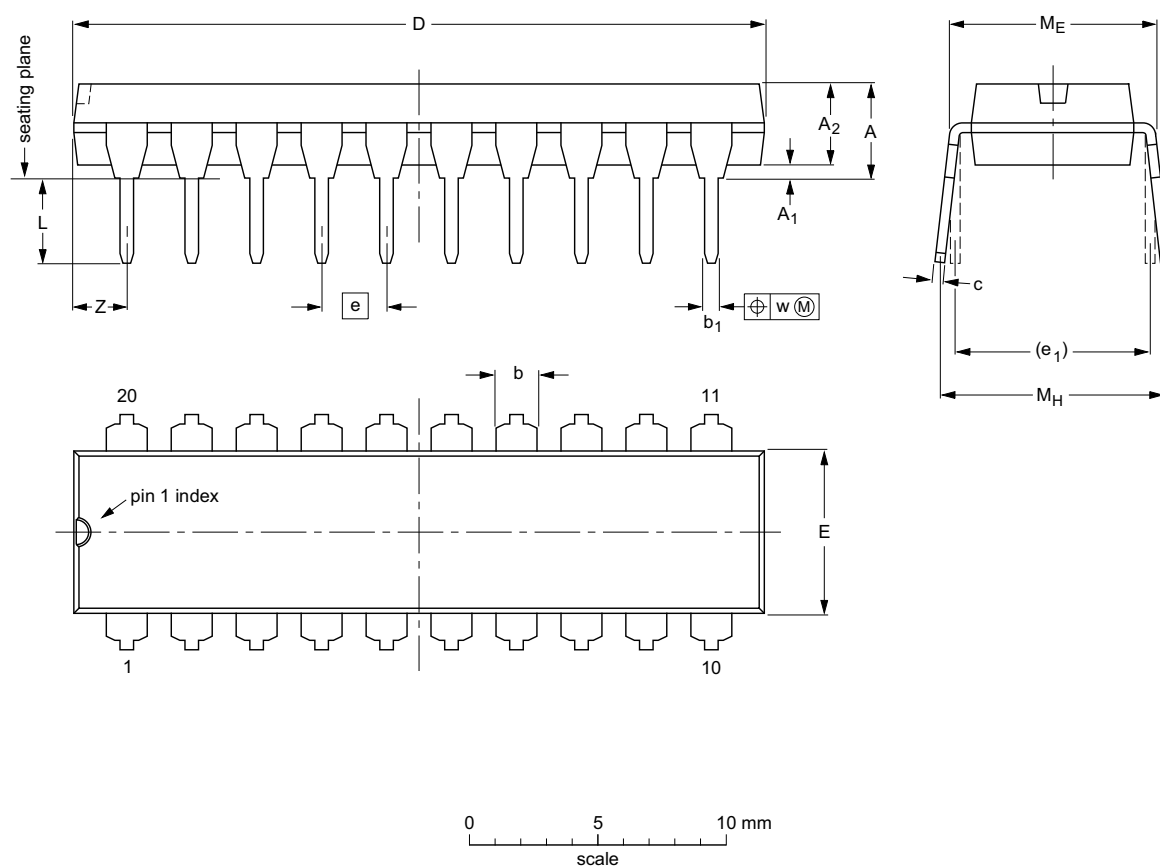
Table 9. Test data

Supply voltage	Input		Load		V_{EXT}		
V_{CC}	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
< 2.7 V	V_{CC}	≤ 2.5 ns	50 pF	1 k Ω	open	GND	$2V_{CC}$
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF, 50 pF	1 k Ω	open	GND	$2V_{CC}$
≥ 4.5 V	V_{CC}	≤ 2.5 ns	50 pF	1 k Ω	open	GND	$2V_{CC}$

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT146-1		MS-001	SC-603			99-12-27 03-02-13

Fig 8. Package outline SOT146-1 (DIP20)

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

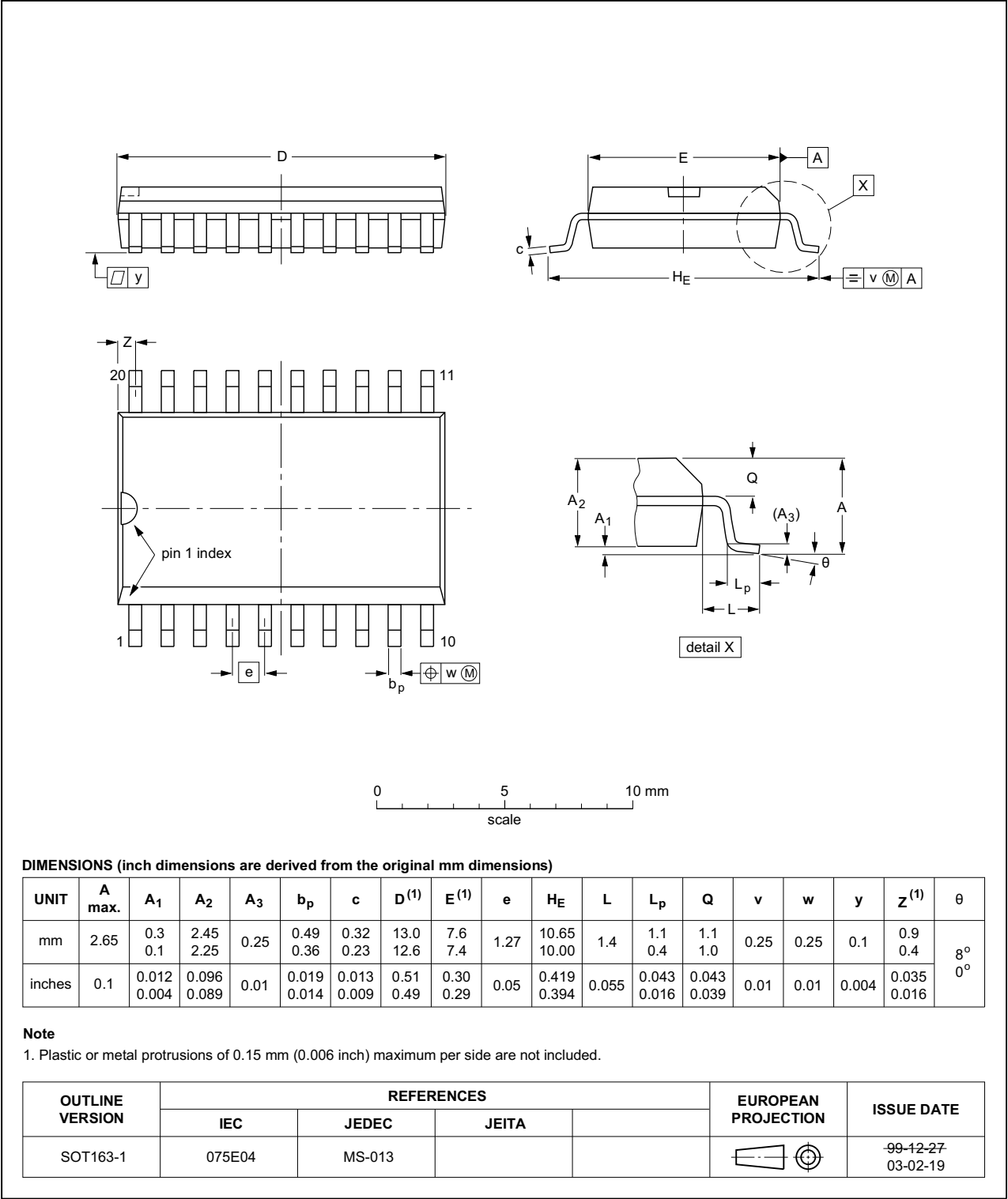


Fig 9. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

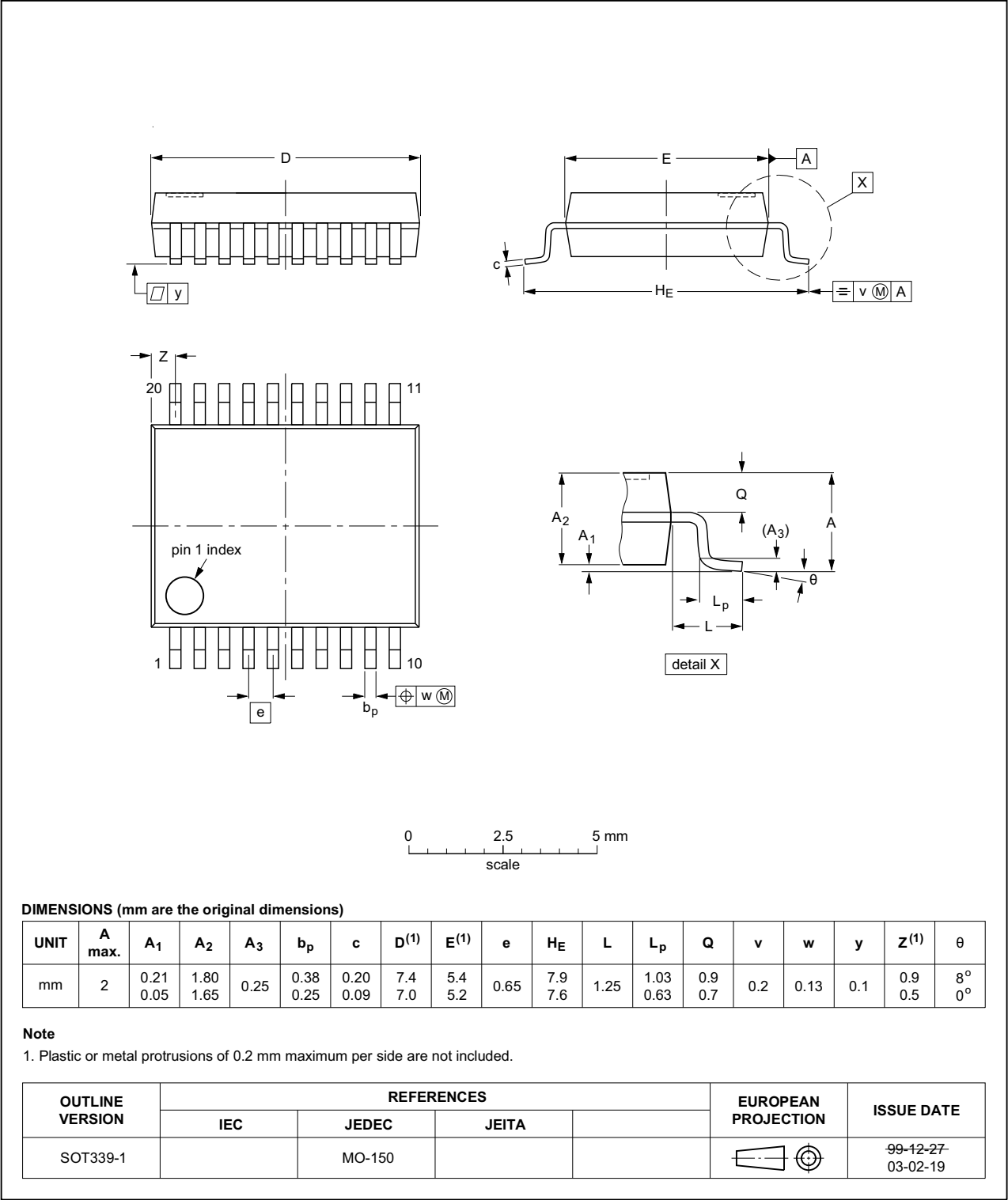


Fig 10. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

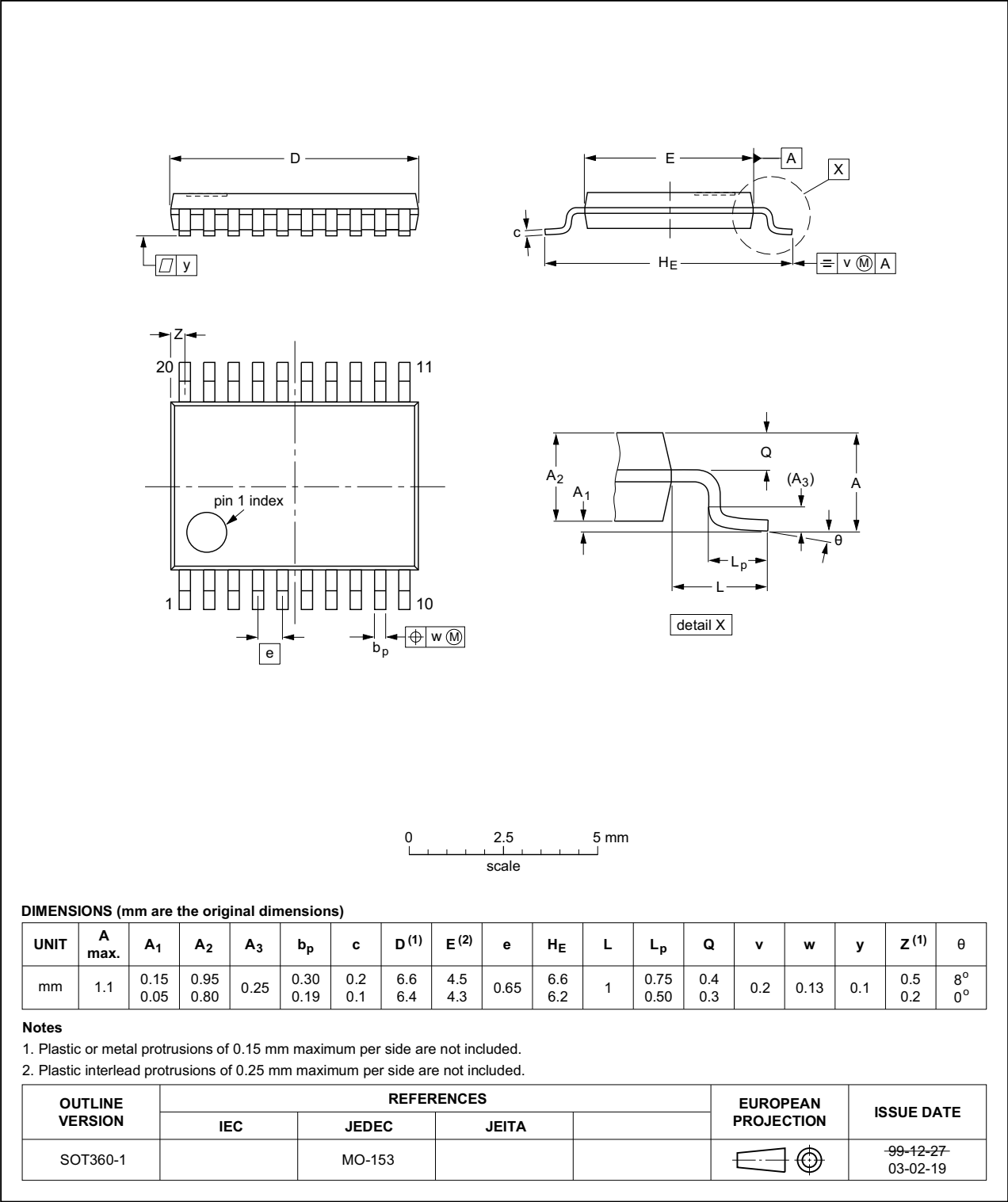


Fig 11. Package outline SOT360-1 (TSSOP20)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV244 v.3	20140311	Product data sheet	-	74LV244 v.2
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate.			
74LV244 v.2	19980520	Product specification	-	74LV244 v.1
74LV244 v.1	-	-	-	-

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15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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